

different orders by pile-up or partial energy deposition. The atomic scattering factor should be determined to a relative accuracy of 10^{-4} which requires that the sample thickness, phase shift and wave length are measured to same accuracy. The absolute wavelength calibration was problematic as the optical interferometer could not be used as absolute reference. Bond method was employed using an analyzer crystal mounted on a Huber rotation table. Up to fifth order was measured at various positions of the rotation table to average non-linearities of the gearbox and inch worm. The phase shift was obtained by comparison of fringe pattern with and without sample.

Fringe pattern were obtained up to fourth order around 540 keV. Si, CaF_2 , Ge, Ag and Sn samples were measured to investigate the Z-dependence of the relativistic correction term. The detailed evaluation is under way.

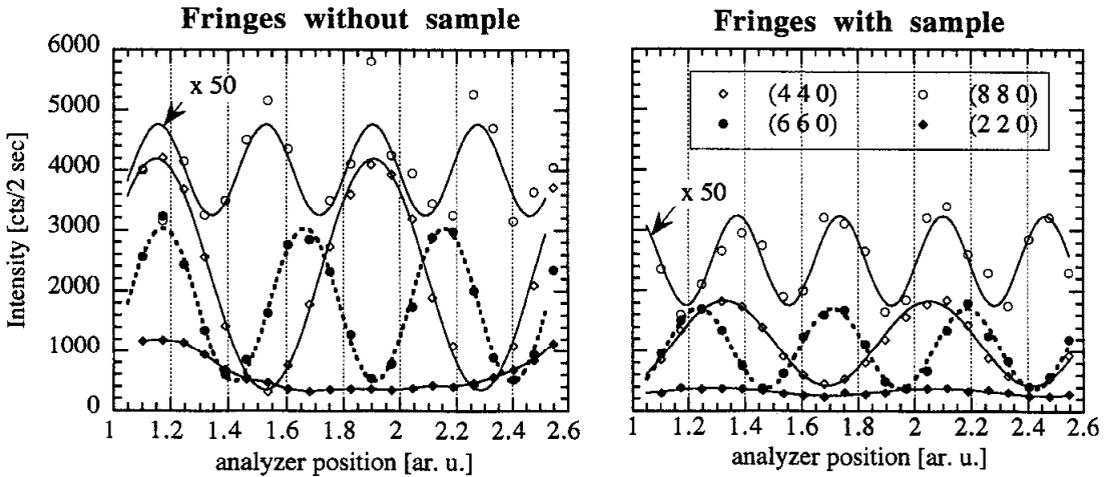


Fig. 1: Fringe pattern to obtain phase shifts by a 5 mm thick Ag sample. The scan without sample gives the reference phase. Note that the zero phases of all harmonics coincide. The fundamental ($E = 135$ keV) is biased by only partial energy deposition by the second order in the Ge-detector. The noise on the fourth order is likely due to pile-up. With inserted sample the phases, intensities and contrast of the different orders vary corresponding to their energy. The fundamental is absorbed by the sample but even the fourth order at 540 keV can be used for phase determination.